



# Data Sheet

KONSEMI eMMC Product  
eMMC 5.1 Specification compatibility

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# Introduction

KONSEMI eMMC is an embedded MMC solution designed in a BGA package form. eMMC operation is identical to a MMC device and therefore is a simple read and write to memory using MMC protocol v5.1 which is a industry standard.

eMMC consists of NAND flash and a MMC controller. 3V supply voltage is required for the NAND area (VDDF) whereas 1.8V supply voltage (VDD or VCCQ) is supported for the MMC controller. KONSEMI eMMC supports HS400 in order to improve sequential bandwidth, especially sequential read performance.

There are several advantages of using eMMC. It is easy to use as the MMC interface allows easy integration with any microprocessor with MMC host. Any revision or amendment of NAND is invisible to the host as the embedded MMC controller insulates NAND technology from the host. This leads to faster product development as well as faster times to market.

The embedded flash management software or FTL (Flash Transition Layer) of eMMC manages Wear Leveling, Bad Block Management and ECC. The FTL supports all features of the different kind of NAND flash and achieves optimal performance.

## 1. Basic Product List

[Table 1] Product Information

| Part No. | NAND Flash Type | Capacity | Density | Power System  | Package size(mm) | Pin Configuration |
|----------|-----------------|----------|---------|---|------------------|-------------------|
| KS81AA80 | 64Gb*1          | 8GB      | 91.7%   | Interface power: VDD (1.70V ~ 1.95V or 2.7V ~ 3.6V)<br>Memory power: VDDF (2.7V ~ 3.6V) | 11.5*13*1        | 153 FBGA          |

## 2. Key Features

### Key Features

- **eMMC5.1 compatible**  
( Backward compatible to eMMC4.5 & eMMC5.0)

- **Bus mode**

- Data bus width: 1bit(default), 4bits, 8bits
- Data transfer rate: up to 400MB/s (HS400)
- MMC I/F Clock frequency: 0~200MHz
- MMC I/F Boot frequency: 0~52MHz

- **Operating Voltage Range**

- Vcc (NAND): 2.7V - 3.6V
- Vccq (Controller): 1.7V - 1.95V / 2.7V ~ 3.6V

- **Temperature**

- Operation (-25°C ~ +85°C)
- Storage without operation (-40°C ~ +85°C)

- **Others**

- This product is compliance with the RoHS directive

### Supported Features

- HS400, HS200
  - HPI, BKOPS, BKOP operation control
  - Packed CMD, CMD queuing
  - Cache, Cache barrier, Cache flushing report
  - Partitioning, RPMB, RPMB throughput improve
  - Discard, Trim, Erase, Sanitize
  - Write protect, Secure write protection
  - Lock/Unlock
  - PON, Sleep/Awake
  - Reliable Write
  - Boot feature, Boot partition
  - HW/SW Reset
  - Field Firmware Update
  - Configurable driver strength
  - Production state awareness
  - Secure removal type
  - Data Strobe pin, Enhanced data strobe
- (Bold features are added in eMMC5.1)

### 3.Package Configuration

#### 3.1 153 Ball map

[Table 2] 153 Ball Information

| Pin NO | Name        |
|--------|-------------|
| A3     | DAT0        |
| A4     | DAT1        |
| A5     | DAT2        |
| B2     | DAT3        |
| B3     | DAT4        |
| B4     | DAT5        |
| B5     | DAT6        |
| B6     | DAT7        |
| K5     | RSTN        |
| C6     | VDD         |
| M4     | VDD         |
| N4     | VDD         |
| P3     | VDD         |
| P5     | VDD         |
| E6     | VDDF        |
| F5     | VDDF        |
| J10    | VDDF        |
| K9     | VDDF        |
| C2     | VDDi        |
| M5     | CMD         |
| H5     | Data Strobe |
| M6     | CLK         |
| J5     | VSS         |
| A6     | VSS         |
| C4     | VSS         |
| E7     | VSS         |
| G5     | VSS         |
| H10    | VSS         |
| K8     | VSS         |
| N2     | VSS         |
| N5     | VSS         |
| P4     | VSS         |
| P6     | VSS         |
| TA2    | URx         |
| TA3    | UTx         |
| TP5    | VCCO-B      |

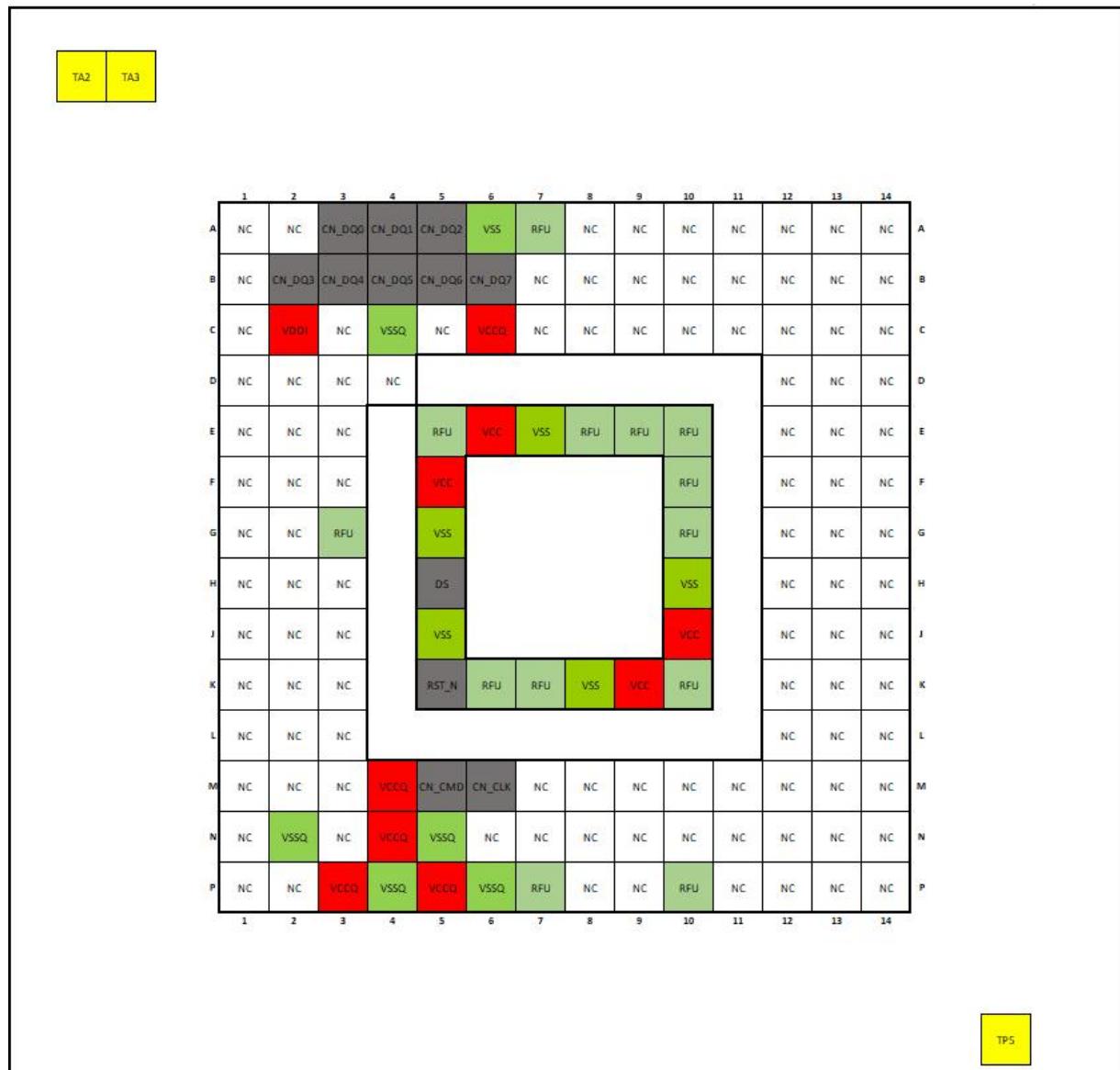


Figure 1 153-FBGA

- ◊ CLK: Clock input
- ◊ Data Strobe: Newly assigned pin for HS400 mode. Data Strobe is generated from eMMC to host.  
In HS400 mode, read data and CRC response are synchronized with Data Strobe.
- ◊ CMD: A bidirectional signal used for device initialization and command transfers.  
Command operates in two modes, open-drain for initialization and push-pull for fast command transfer.
- ◊ DAT0-7: Bidirectional data channels. It operates in push-pull mode.
- ◊ RSTN: H/W reset signal pin
- ◊ VDDF(VCC): Supply voltage for flash memory
- ◊ VDD(VCCQ): Supply voltage for memory controller
- ◊ VDDi: Internal power node to stabilize regulator output to controller core logics
- ◊ VSS: Ground connections
- ◊ RFU: Reserved for future use, do not use for any usage

### 3.1.1 11.5mm x 13mm x 1mm Package Dimension

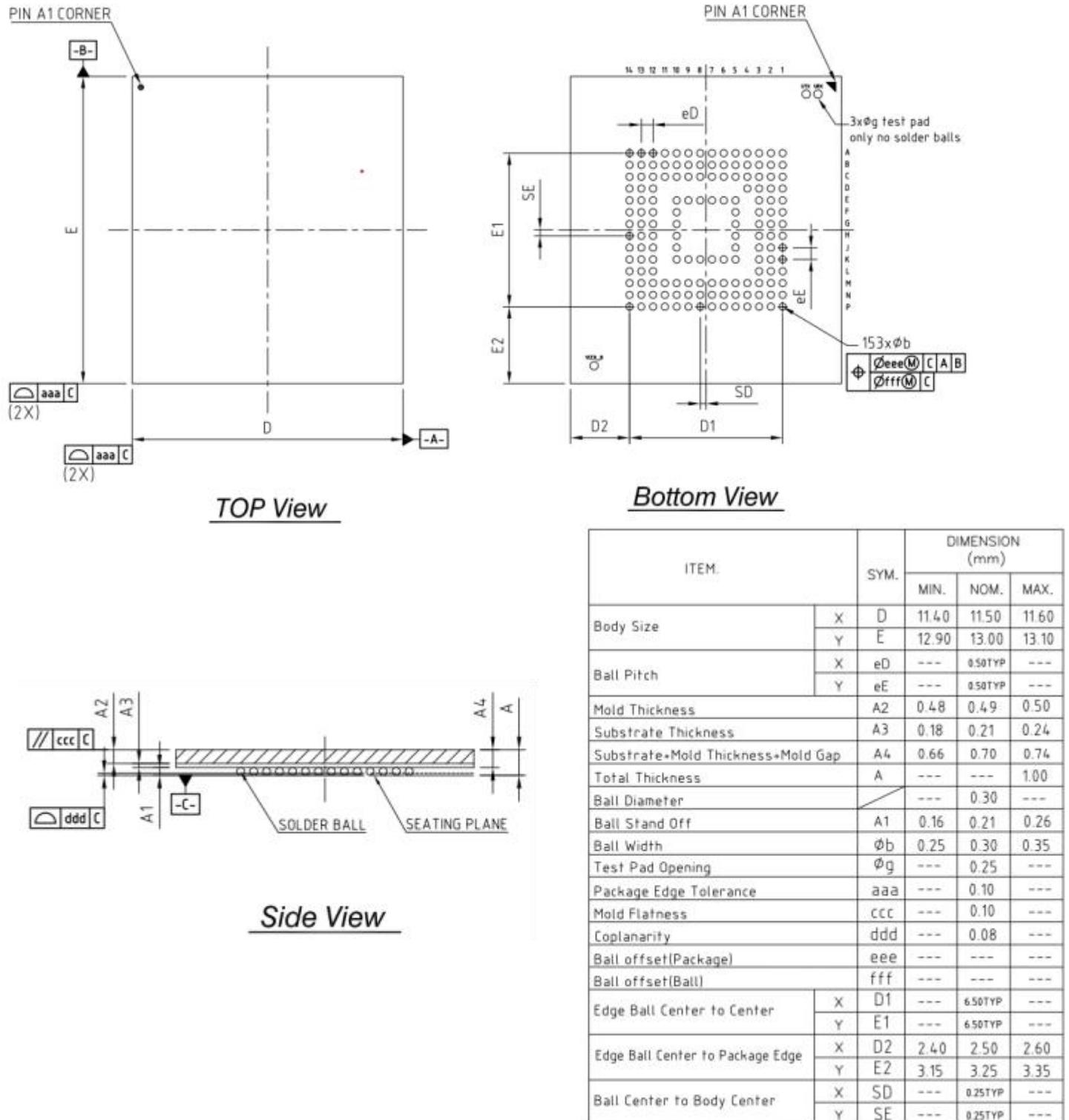


Figure 2 11.5mm x 13mm x 1mm Package Dimension

### 3.2 Block Diagram

eMMC consists of NAND Flash and Controller. VDD (VCCQ) is for Controller power and VDDF (VCC) is for flash power

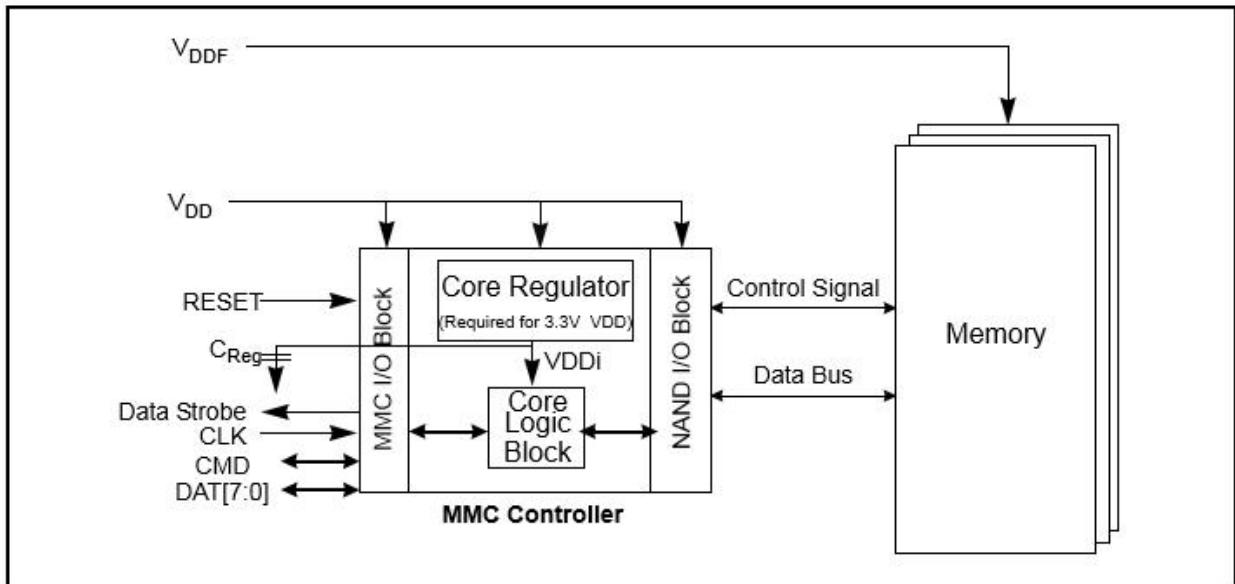


Figure 3. eMMC Block Diagram

### 3.3 Reference schematic

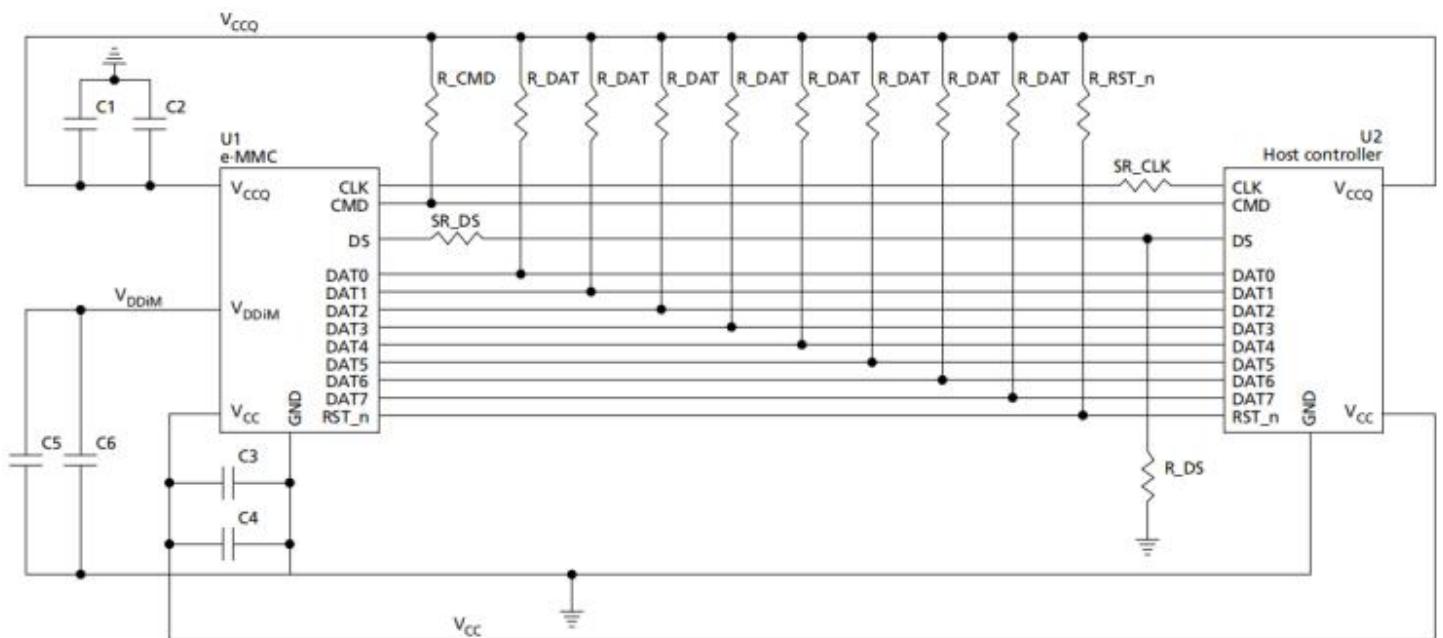


Figure 4. eMMC reference schematic

**Table 3-1 Component Parameter Values**

| <b>Parameter</b>                       | <b>Symbol</b> | <b>Min</b> | <b>Max</b> | <b>Recom-mended</b> | <b>Unit</b> | <b>Comments</b>   |
|--|---------------|------------|------------|---------------------|-------------|---|
| Pull-up resistance for CMD             | R_CMD         | 4.7        | 50         | 10                  | KΩ          | To prevent bus floating   |
| Pull-up resistance for DAT[7:0]        | R_DAT         | 10         | 50         | 50                  | KΩ          | To prevent bus floating   |
| Pull-up resistance for RST_n           | R_RST_n       | 4.7        | 50         | 50                  | KΩ          | It is not necessary to put pull-up resistance on RST_n line if the host does not use H/W reset.             |
| Pull-down resistance for R_DS          | R_DS          | 10         | 100        | -                   | KΩ          |   |
| Impedance of CLK/CMD/DS/<br>DAT[7:0]   | -             | 45         | 55         | 50                  | Ω           | Impedance match   |
| Serial resistance on CLK line          | SR_CLK        | 0          | 47         | 22                  | Ω           | To stabilize CLK signal   |
| Serial resistance on DS line           | SR_DS         | 0          | 47         | 22                  | Ω           | To stabilize DS signal  |
| V <sub>CCQ</sub> capacitor value       | C1, C2        | 2.2 + 0.1  | 4.7 + 0.22 | 2.2 + 0.1           | μF          | Decoupling capacitor should be connected with V <sub>CCQ</sub> and V <sub>SSQ</sub> as closely as possible. |
| V <sub>CC</sub> capacitor value (≤8GB) | C3, C4        | 2.2 + 0.1  | 4.7 + 0.22 | 2.2 + 0.1           | μF          | Decoupling capacitor should be connected to V <sub>CC</sub> and V <sub>SS</sub> as closely as possible.     |
| V <sub>CC</sub> capacitor value (>8GB) |               |            |            | 4.7 + 0.22          | μF          |   |
| V <sub>DDIM</sub> capacitor value      | C5, C6        | 1 + 0.1    | 4.7 + 0.1  | 1 + 0.1             | μF          | Decoupling capacitor should be connected to V <sub>DDIM</sub> and V <sub>SSQ</sub> as closely as possible.  |

## 4.HS400 mode

eMMC5.1 product supports high speed DDR interface timing mode up to 400MB/s at 200MHz with 1.8V I/O supply.

HS400 mode supports the following features:

- DDR Data sampling method

- CLK frequency up to 200MHz DDR – up to 400Mbps

- Only 8-bits bus width available

- Signaling levels of 1.8V

- Five optional Drive Strength (refer to the table below)

[Table 3] I/O driver strength types

| Driver Type | HS200 & HS400 Support | Nominal Impedance | Approximated driving capability compared to Type-0 | Remark   |
|-------------|-----------------------|-------------------|--|--|
| 0X0         | Mandatory             | 50Ω               | x1   | Default Driver Type.<br>Supports up to 200MHz operation.                                     |
| 0X1         | Optional              | 33Ω               | x1.5   | Supports up to 200MHz Operation.   |
| 0X2         | Optional              | 66Ω               | x0.75  | The weakest driver that supports up to 200MHz operation.                                     |
| 0X3         | Optional              | 100Ω              | x0.5   | For low noise and low EMI systems.<br>Maximal operating frequency is decided by Host design. |
| 0X4         | Optional              | 40Ω               | x1.2   | Supports up to 200MHz DDR operation  |

NOTE:1) Support of Driver Type-0 is mandatory for HS200 & HS400 Device.

NOTE:2) Nominal impedance is defined by I-V characteristics of output driver at 0.9V when V<sub>CCQ</sub>=1.8V

NOTE:3) Nominal impedance is defined by I-V characteristics of output driver at 0.6V when V<sub>CCQ</sub>=1.2V

[Table 4] Device type values (EXT\_CSD register: DEVICE\_TYPE [196])

| Bit | Device Type   | Supportability |
|-----|---|----------------|
| 7   | HS400 Dual Data Rate eMMC @ 200 MHz - 1.2V I/O          | Not support    |
| 6   | HS400 Dual Data Rate eMMC @ 200 MHz - 1.8V I/O          | Support        |
| 5   | HS200 Single Data Rate eMMC @ 200 MHz - 1.2V I/O        | Not support    |
| 4   | HS200 Single Data Rate eMMC @ 200 MHz - 1.8V I/O        | Support        |
| 3   | High-Speed Dual Data Rate eMMC @ 52MHz - 1.2V I/O       | Not support    |
| 2   | High-Speed Dual Data Rate eMMC @ 52MHz - 1.8V or 3V I/O | Support        |
| 1   | High-Speed eMMC @ 52MHz - at rated device voltage(s)    | Support        |
| 0   | High-Speed eMMC @ 26MHz - at rated device voltage(s)    | Support        |

[Table 5] Extended CSD revisions (EXT\_CSD register: EXT\_CSD\_REV [192])

| Value | Timing Interface                   | EXT_CSD Register Value |
|-------|------------------------------------|------------------------|
| 255-8 | Reserved                           | -                      |
| 8     | Revision 1.8 (for MMC V5.1)        | 0x08                   |
| 7     | Revision 1.7 (for MMC V5.0)        | -                      |
| 6     | Revision 1.6 (for MMC V4.5, V4.51) | -                      |
| 5     | Revision 1.5 (for MMC V4.41)       | -                      |
| 4     | Revision 1.4 (Obsolete)            | -                      |
| 3     | Revision 1.3 (for MMC V4.3)        | -                      |
| 2     | Revision 1.2 (for MMC V4.2)        | -                      |
| 1     | Revision 1.1 (for MMC V4.1)        | -                      |
| 0     | Revision 1.0 (for MMC V4.0)        | -                      |

[Table 6] High speed timing values (EXT\_CSD register: HS\_TIMING [185])

| Value | Timing Interface                                   | Supportability |
|-------|--|----------------|
| 0x0   | Selecting backwards compatibility interface timing | Support        |
| 0x1   | High Speed   | Support        |
| 0x2   | HS200  | Support        |
| 0x3   | HS400  | Support        |

## 5.New eMMC5.1 Features

### 5.1 Overview

| New Feature                  | JEDEC     | Support |
|------------------------------|-----------|---------|
| Cache Flushing Report        | Mandatory | Yes     |
| Background operation control | Mandatory | Yes     |
| Command Queuing              | Optional  | Yes     |
| Enhanced Strobe              | Optional  | Yes     |
| RPMB Throughput improve      | Optional  | Yes     |
| Secure Write Protection      | Optional  | No      |

### 5.2 Command Queuing

To facilitate command queuing in eMMC, the device manages an internal task queue that the host can queue during data transfer tasks.

Every task is issued by the host and initially queued as pending. The device works to prepare pending tasks for execution. When a task is ready for execution, its state changes to "ready for execution".

The host tracks the state of all queued tasks and may order the execution of any task, marked as "ready for execution", by sending a command indicating its task ID. The device executes the data transfer transaction after receiving the execute command (CMD46/CMD47)

#### 5.2.1 CMD Set Description

[Table 7] CMD Set Description and Details

| CMD   | Type    | Argument  | Abbreviation         | Purpose  |
|-------|---------|---|----------------------|--|
| CMD44 | ac/R1   | [31] Reliable Write Request<br>[30] DAT_DIR - "0" write / "1" read<br>[29] tag request<br>[28:25] context ID<br>[24] forced programming<br>[23] Priority: "0" simple / "1" high<br>[20:16] TASK ID<br>[15:0] number of blocks | QUEUED_TASK_PARAMS   | Define direction of operation (Read or Write) and set high priority CMD Queue with task ID   |
| CMD45 | ac/R1   | [31:0] Start block address  | QUEUED_TASK_ADDRES S | Indicate data address for Queued CMD   |
| CMD46 | adtc/R1 | [20:16] TASK ID   | EXECUTE_READ_TASK    | (Read) Transmit the requested number of data blocks  |
| CMD47 | adtc/R1 | [20:16] TASK ID   | EXECUTE_WRITE_TASK   | (Write) Transmit the requested number of data blocks   |
| CMD48 | ac/R1b  | [20:16] Task ID<br>[3:0] TM op-code   | CMDQ_TASK_MGMT       | Reset a specific task or entire queue.<br>[20:16] when TM op-code = 2h these bits represent Task ID<br>When TM op-code = 1h these bits are reserved" |

#### 5.2.2 New Response: QSR (Queue Status Register)

The 32-bit Queue Status Register (QSR) carries the state of tasks in the queue at a specific point in time. The host has read access to this register through device response to SEND\_STATUS command (CMD13 with bit [15] = "1"), R1's argument will be the 32-bit Queue Status Register (QSR). Every bit in the QSR represents the task whose ID corresponds to the bit index. If bit QSR[i] = "0", then the queued task with a Task ID i is not ready for execution. The task may be queued and pending, or the Task ID is unused. If bit QSR[i] = "1", then the queued task with Task ID i is ready for execution.

#### 5.2.3 Send Status: CMD13

CMD13 for reading the Queue Status Register (QSR) by the host. If bit [15] in CMD13's argument is set to 1, then the device shall send an R1 Response with the QSR instead of the Device Status. \* There is still legacy CMD13 with R` response

## 5.2.4 Mechanism of CMD Queue operation

Host issues CMD44 with Task ID number, Sector, Count, Direction, Priority to the device followed by CMD45 and host checks the Queue Status check with CMD13 [15] bits to 1. After that host issues CMD46 for Read or CMD47 for write During CMD queue operation, CMD44/CMD45 is able to be issued at any time when the CMD line is not in use

## 5.2.5 CMD Queue Register description

Configuration and capability structures shall be added to the EXT\_CSD register, as described below

[Table 8] CMD Queuing Support (EXT\_CSD register: CMDQ\_SUPPORT [308])

| Bit7 | Bit6 | Bit5 | Bit4     | Bit3 | Bit2 | Bit1 | Bit0                |
|------|------|------|----------|------|------|------|---------------------|
|      |      |      | Reserved |      |      |      | CMD Queue supported |

This field indicates whether the device supports command queuing or not

0x0: CMD Queue function is not supported

0x1: CMD Queue function is supported

[Table 9] Command Queue Mode Enable (EXT\_CSD register: CMDQ\_MODE\_EN [15])

| Bit7 | Bit6 | Bit5 | Bit4     | Bit3 | Bit2 | Bit1 | Bit0 |
|------|------|------|----------|------|------|------|------|
|      |      |      | Reserved |      |      |      | -    |

This field is used by the host enable command queuing

0x0: Queue function is not enabled

0x1: Queue function is enabled

[Table 10] CMD Queuing Depth (EXT\_CSD register: CMDQ\_DEPTH [307])

| Bit7 | Bit6     | Bit5 | Bit4 | Bit3 | Bit2 | Bit1 | Bit0 |
|------|----------|------|------|------|------|------|------|
|      | Reserved |      |      |      |      | N    |      |

This field is used to calculate the depth of the queue supported by the device

Bit encoding:

[7:5]: Reserved

[4:0]: N, a parameter used to calculate the Queue Depth of task queue in the device.

Queue Depth = N+1.

## 5.3 Enhanced Strobe Mode

This product supports Enhanced Strobe in HS400 mode and refer to the details as described in eMMC5.1 JEDEC standard

## 5.4 RPMB Throughput improve

[Table 11] Related parameter register in EXT\_CSD: WR\_REL\_PARAM [166]

| Name                         | Field          | Bit | Type |
|------------------------------|----------------|-----|------|
| Enhanced RPMB Reliable Write | EN_RPMB_REL_WR | 4   | R    |

Bit [4]: EN\_RPMB\_REL\_WR(R)

0x0: RPMB transfer size is either 256B (single 512B frame) or 512B (Two 512B frame).

0x1: RPMB transfer size is either 256B (single 512B frame), 512B (Two 512B frame), or 8KB (Thirty-two 512B frames).

## 5.5 Secure Write Protection

Configuration and capability structures shall be added to the EXT\_CSD register and Authenticated Device Configuration Area as described below

[Table 12] Parameter register in EXT\_CSD: SECURE\_WP\_INFO [211]

| Bit7 | Bit6 | Bit5     |  | Bit4 | Bit3 | Bit2 | Bit1                | Bit0              |
|------|------|----------|--|------|------|------|---------------------|-------------------|
|      |      | Reserved |  |      |      |      | SECURE_WP_EN_STATUS | SECURE_WP_SUPPORT |

Bit [7:2]: Reserved

Bit [1]: SECURE\_WP\_EN\_STATUS(R)

0x0: Legacy Write Protection mode.

0x1: Secure Write Protection mode.

Bit [0]: SECURE\_WP\_SUPPORT(R)

0x0: Secure Write Protection is NOT supported by this device

0x1: Secure Write Protection is supported by this device

[Table 13] Authenticated Device Configuration Area [1]: SECURE\_WP\_MODE\_ENABLE

| Bit7 | Bit6 | Bit5 |          | Bit4 | Bit3 | Bit2 | Bit1 | Bit0 |
|------|------|------|----------|------|------|------|------|------|
|      |      |      | Reserved |      |      |      |      | 0x00 |

Bit [7:1]: Reserved

Bit [0]: SECURE\_WP\_EN (R/W/E)

The default value of this field is 0x0.

x 0x0: Legacy Write Protection mode, i.e., TMP\_WRITE\_PROTECT [12],

PERM\_WRITE\_PROTECT [13] is updated by CMD27. USER\_WP [171], BOOT\_WP [173]

and BOOT\_WP\_STATUS [174] are updated by CMD6.

x 0x1: Secure Write Protection mode. The access to the write protection related EXT\_CSD and

CSD fields depends on the value of SECURE\_WP\_MASK bit in

SECURE\_WP\_MODE\_CONFIG field.

[Table 14] Authenticated Device Configuration Area [2]: SECURE\_WP\_MODE\_CONFIG

| Bit7 | Bit6 | Bit5 |          | Bit4 | Bit3 | Bit2 | Bit1 | Bit0 |
|------|------|------|----------|------|------|------|------|------|
|      |      |      | Reserved |      |      |      |      | 0x00 |

Bit [7:1]: Reserved

Bit [0] : SECURE\_WP\_MASK (R/W/E\_P)

The default value of this field is 0x0.

x 0x0: Disabling updating WP related EXT\_CSD and CSD fields. CMD27 (Program CSD) will generate generic error for setting

TMP\_WRITE\_PROTECT [12], PERM\_WRITE\_PROTECT [13]. CMD6 for updating USER\_WP [171], BOOT\_WP [173] and

BOOT\_WP\_STATUS [174] generates SWITCH\_ERROR. If a force erase command is issued, the command will fail (Device stays locked) and

the LOCK\_UNLOCK\_FAILED error bit will be set in the status register. If CMD28 or CMD29 is issued, then generic error will be occurred.

Power-on Write Protected boot partitions will keep protected mode after power failure, H/W reset assertion and any CMD0 reset. The device keeps the current value of BOOT\_WP\_STATUS in the EXT\_CSD register to be same after power cycle, H/W reset assertion, and any CMD0 reset.

x 0x1: Enabling updating WP related EXT\_CSD and CSD fields. I.e., TMP\_WRITE\_PROTECT [12], PERM\_WRITE\_PROTECT [13],  
USER\_WP [171], BOOT\_WP [173] and BOOT\_WP\_STATUS [174] are accessed using CMD6, CMD8 and CMD27.

If a force erase command is issued and accepted, then ALL THE DEVICE CONTENT WILL BE ERASED including the PWD and PWD\_LEN register content and the locked Device will get unlocked. If a force erase command is issued and power-on protected or a permanently-write-protected write protect groups exist on the device, the command will fail (Device stays locked) and the LOCK\_UNLOCK\_FAILED error bit will be set in the status register. An attempt to force erase on an unlocked Device will fail and LOCK\_UNLOCK\_FAILED error bit will be set in the status register. Write Protection is applied to the WPG indicated by CMD28 with the WP type indicated by the bit [2] and bit [0] of USER\_WP [171]. All temporary WP Groups and power-on Write Protected boot partitions become writable/erasable temporarily which means write protect type is not changed. All power-on and permanent WP Groups in user area will not become writable/erasable temporarily. Those temporarily writable/erasable area will become write protected when this bit is cleared to 0x0 by the host or when there is power failure, H/W reset assertion and any CMD0 reset. The device keeps the current value of BOOT\_WP\_STATUS in the EXT\_CSD register to be same after power cycle, H/W reset assertion, and any CMD0 reset.

## 5.6 Field Firmware Upgrade

Field firmware upgrade (FFU) provide an effective way to do features modified in the field. By this way, host downloads new firmware to the eMMC device and enable the device to install the new downloaded firmware, the whole FFU process will not affect the user or OS data. During the FFU process, the host can replace firmware or single/all systems.

Please refer to following FFU operation guideline:

| Step | CMD Index | CMD Argument | Data    | Other Action & Note                         |
|------|-----------|--------------|---------|---|
| 1    |           |              |         | Power Off *1                                |
| 2    |           |              |         | Delay 500ms *2                              |
| 3    |           |              |         | Power On *3                                 |
| 4    |           |              |         | Delay 500ms                                 |
| 5    |           |              |         | Set Host Clock 375KHz *4                    |
| 6    |           |              |         | Set Host Bus Width to 1-bit *5              |
| 7    |           |              |         | Delay 100ms                                 |
| 8    | CMD0      | 0x00000000   |         | eMMC Vendor CMD<br>Expect no response       |
| 9    | CMD1      | 0x40FF8080   |         | Check Response until ready<br>(C0 FF 80 80) |
| 10   | CMD2      | 0x00000000   |         |   |
| 11   | CMD3      | 0x00020000   |         |   |
| 12   | CMD7      | 0x00020000   |         |   |
| 13   | CMD13     | 0x00020000   |         | Check Response until ready<br>(00 00 09 00) |
| 14   | CMD6      | 0x031E0100   |         | Enter FFU Mode                              |
| 15   | CMD13     | 0x00020000   |         | Check Response until ready<br>(00 00 09 00) |
| 16   | CMD25     | 0x1FCA0000   | ffu.bin | Write" ffu.bin "into devices                |
| 17   | CMD12     | 0x00020000   |         |   |
| 18   | CMD13     | 0x00020000   |         | Check Response until ready<br>(00 00 09 00) |
| 19   | CMD6      | 0x031D0100   |         | Enter FFU Install                           |
| 20   |           |              |         | Power Off                                   |
| 21   |           |              |         | Delay 500ms                                 |
| 22   |           |              |         | Power On                                    |
| 23   |           |              |         | Delay 500ms                                 |

**Note:**

- \*1. Cutting off VCC, VCCQ supply
- \*2. Delay 500mS
- \*3. Resume VCC, VCCQ supply
- \*4. Switch the CLK to 375KHz on the Host
- \*5. Switch the Bus Width to 1-bit on the Host

## 6. Technical Notes

### 6.1 S/W Algorithm

#### 6.1.1 Partition Management

The device initially consists of two Boot Partitions and RPMB Partition and User Data Area.

The User Data Area can be divided into four General Purpose Area Partitions and User Data Area partition. Each of the General-purpose Area partitions and a section of User Data Area partition can be configured as enhanced partition.

##### 6.1.1.1 Enhanced Partition (Area)

KONSEMI eMMC adopts Enhanced User Data Area as SLC Mode. Therefore, when master adopts some portion as enhanced user data area in User Data Area, that area occupies double size of original set up size. (<ex> if master set 1MB for enhanced mode, total 3MB user data area is needed to generate 1MB enhanced area)

Max Enhanced User Data Area size is defined as (MAX\_ENH\_SIZE\_MULT x HC\_WP\_GRP\_SIZE x HC\_ERASE\_GRP\_SIZE x 512kBytes)

## 6.1.2 Boot operation

Device supports not only boot mode but also alternative boot mode. Device supports high speed timing and dual data rate during boot.

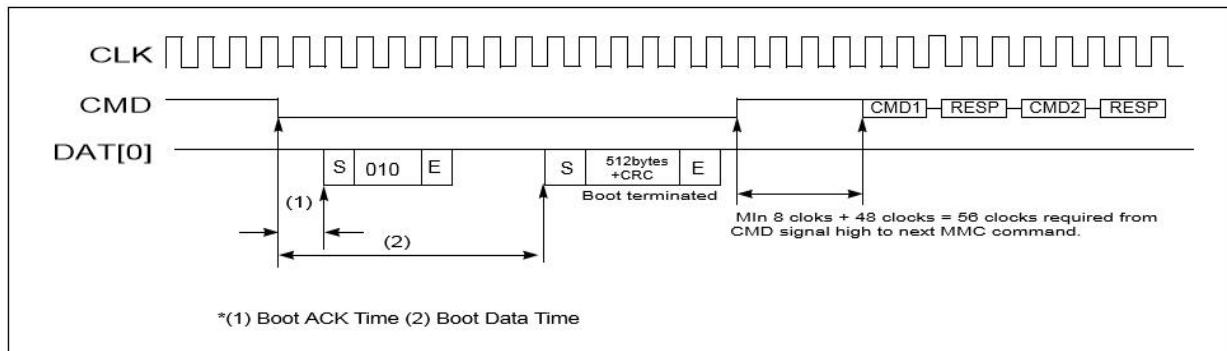


Figure 5. embedded Multi-Media Card state diagram (boot mode)

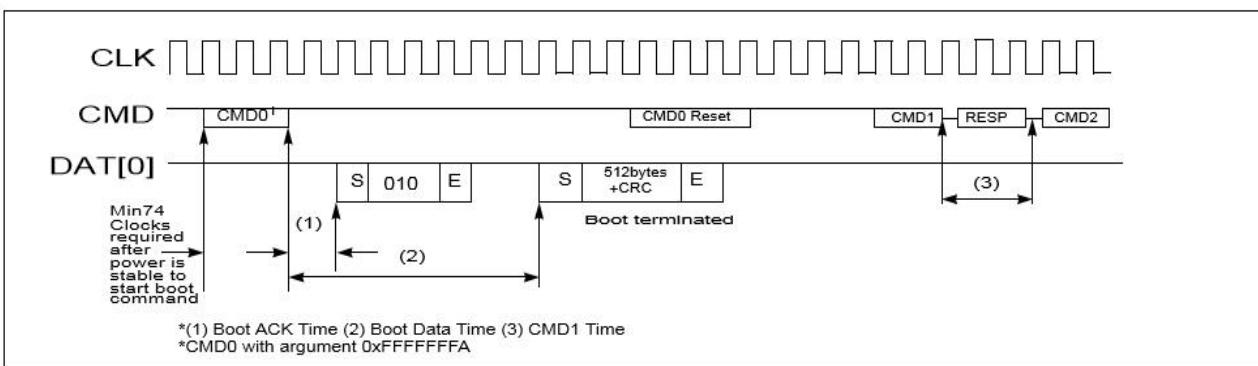


Figure 6. embedded Multi-Media Card state diagram (alternative boot mode)

[Table 15] Boot ack, boot data and initialization Time

| Timing Factor             | Value    |
|---------------------------|----------|
| (1) Boot ACK Time         | < 50 mS  |
| (2) Boot Data Time        | < 150 mS |
| (3) Initialization Time1) | < 3 Sec  |

### NOTE:

- 1) This initialization time includes partition setting, please refer to INI\_TIMEOUT\_AP in 6.4 Extended CSD Register.  
Normal initialization time (without partition setting) is completed within 1sec

### 6.1.3 User Density

Total User Density depends on device type.  
 For example, 32MB in the SLC Mode requires 64MB in MLC.  
 This results in decreasing of user density

[Table 16] Capacity according to partition

|          | Boot partition 1 | Boot partition 2 | RPMB    |
|----------|------------------|------------------|---------|
| Default. | 4,096KB          | 4,096KB          | 4,096KB |
| Max.     | 4,096KB          | 4,096KB          | 4,096KB |

[Table 17] Maximum Enhanced Partition Size

| Device |
|--------|
| 8 GB   |

[Table 18] User Density Size

| Device | User Density Size   |
|--------|---------------------|
| 8 GB   | 7,851,737,088 Bytes |

### 6.1.4 Auto Power Saving Mode

If host does not issue any command during a certain duration (10ms), after previously issued command is completed, the device enters "Power Saving mode" to reduce power consumption.

At this time, commands arrive at the device while it is in power saving mode will be serviced in normal fashion

[Table 19] Auto Power Saving Mode enter and exit

[Table 20] Auto Power Saving Mode and Sleep Mode

| Mode                   | Enter Condition   | Escape Condition           |
|------------------------|---|----------------------------|
| Auto Power Saving Mode | When previous operation which came from Host is completed and no command is issued during a certain time. | If Host issues any command |

|                  | Auto Power Saving Mode | Sleeping Mode |
|------------------|------------------------|---------------|
| NAND Power       | ON                     | OFF           |
| Go to Sleep Time | > 100 mS               | < 55 mS       |

### 6.1.5 Performance

[Table 21] Performance

| Density | Sequential Read (MB/s) | Sequential Write (MB/s) |
|---------|------------------------|-------------------------|
| 8 GB    | Up to 140 MB/S         | Up to 110 MB/S          |

\* Test Condition: Bus width x8, HS400, 512KB data transfer, test on card reader (Secondary drive) clean state.

## 7. Register Value

### 7.1 OCR Register

The 32-bit operation conditions register stores the VDD voltage profile of the eMMC. In addition, this register includes a status information bit. This status bit is set if the eMMC power up procedure has been finished. The OCR register shall be implemented by all eMMCs.

[Table 22] OCR Register

| OCR bit | VDD voltage window <sup>2</sup> | Register Value   |
|---------|---------------------------------|--|
| [6:0]   | Reserved                        | 00 0000b   |
| [7]     | 1.70 - 1.95                     | 1b   |
| [14:8]  | 2.0-2.6                         | 000 0000b  |
| [23:15] | 2.7-3.6                         | 1 1111 1111b   |
| [28:24] | Reserved                        | 0 0000b  |
| [30:29] | Access Mode                     | 00b (byte mode) 10b (sector mode) - [ *Higher than 2GB only] |
| [31]    |                                 | eMMC power up status bit (busy) <sup>1</sup>                 |

**NOTE:**

- 1) This bit is set to LOW if the eMMC has not finished the power up routine
- 2) The voltage for internal flash memory (VDDF) should be 2.7-3.6v regardless of OCR Register value.

### 7.2 CID Register

[Table 23] CID Register

| Name                  | Field | Width | CID-slice | CID Value              |
|-----------------------|-------|-------|-----------|------------------------|
| Manufacturer ID       | MID   | 8     | [127:120] | 0x2F                   |
| Reserved              |       | 6     | [119:114] | ---                    |
| Card/BGA              | CBX   | 2     | [113:112] | 0x01                   |
| OEM/Application ID    | OID   | 8     | [111:104] | 0x11                   |
| Product name          | PNM   | 48    | [103:56]  | See Product name table |
| Product revision      | PRV   | 8     | [55:48]   | ---2                   |
| Product serial number | PSN   | 32    | [47:16]   | ---3                   |
| Manufacturing date    | MDT   | 8     | [15:8]    | ---4                   |
| CRC7 checksum         | CRC   | 7     | [7:1]     | ---5                   |
| not used, always '1'  | -     | 1     | [0:0]     | 0x01                   |

**NOTE:**

- 1),4),5) description are same as eMMC JEDEC standard
- 2) PRV is composed of the revision count of controller and the revision count of F/W patch
- 3) A 32 bits unsigned binary integer. (Random Number)

#### 7.2.1 Product name table (In CID Register)

[Table 24] Product name table

| Part Number | Density | Product Name in CID Register (PNM) |
|-------------|---------|------------------------------------|
| KS81AA80    | 8 GB    | 0x303553303030                     |

## 7.3 CSD Register

The Card-Specific Data register provides information on how to access the eMMC contents. The CSD defines the data format, error correction type, maximum data access time, data transfer speed, whether the DSR register can be used etc. The programmable part of the register (entries marked by W or E, see below) can be changed by CMD27. The type of the entries in the table below is coded as follows: R: Read only

W: One time programmable and not readable.

R/W: One time programmable and readable.

W/E: Multiple writable with value kept after power failure, H/W reset assertion and any CMD0 reset and not readable.

R/W/E: Multiple writable with value kept after power failure, H/W reset assertion and any CMD0 reset and readable.

R/W/C\_P: Writable after value cleared by power failure and HW/ rest assertion (the value not cleared by CMD0 reset) and readable.

R/W/E\_P: Multiple writable with value reset after power failure, H/W reset assertion and any CMD0 reset and readable.

W/E/\_P: Multiple writable with value reset after power failure, H/W reset assertion and any CMD0 reset and not readable.

[Table 25] CSD Register

| Name   | Field              | Width | Cell Type | CSD slice | CSD Value |
|--|--------------------|-------|-----------|-----------|-----------|
|  |                    |       |           |           | 8GB       |
| CSD structure                                    | CSD_STRUCTURE      | 2     | R         | [127:126] | 0x03      |
| System specification version                     | SPEC_VERS          | 4     | R         | [125:122] | 0x04      |
| Reserved   | -                  | 2     | R         | [121:120] | -         |
| Data read access-time 1                          | TAAC               | 8     | R         | [119:112] | 0x4F      |
| Data read access-time 2 in CLK cycles (NSAC*100) | NSAC               | 8     | R         | [111:104] | 0x00      |
| Max. bus clock frequency                         | TRAN_SPEED         | 8     | R         | [103:96]  | 0x32      |
| Device command classes                           | CCC                | 12    | R         | [95:84]   | 0x9F5     |
| Max. read data block length                      | READ_BL_LEN        | 4     | R         | [83:80]   | 0x09      |
| Partial blocks for read allowed                  | READ_BL_PARTIAL    | 1     | R         | [79:79]   | 0x00      |
| Write block misalignment                         | WRITE_BLK_MISALIGN | 1     | R         | [78:78]   | 0x00      |
| Read block misalignment                          | READ_BLK_MISALIGN  | 1     | R         | [77:77]   | 0x00      |
| DSR implemented                                  | DSR_IMP            | 1     | R         | [76:76]   | 0x00      |
| Reserved   | -                  | 2     | R         | [75:74]   | -         |
| Device size                                      | C_SIZE             | 12    | R         | [73:62]   | 0xFFFF    |
| Max. read current @ VDD min                      | VDD_R_CURR_MIN     | 3     | R         | [61:59]   | 0x07      |
| Max. read current @ VDD max                      | VDD_R_CURR_MAX     | 3     | R         | [58:56]   | 0x07      |
| Max. write current @ VDD min                     | VDD_W_CURR_MIN     | 3     | R         | [55:53]   | 0x07      |
| Max. write current @ VDD max                     | VDD_W_CURR_MAX     | 3     | R         | [52:50]   | 0x07      |
| Device size multiplier                           | C_SIZE_MULT        | 3     | R         | [49:47]   | 0x7       |
| Erase group size                                 | ERASE_GRP_SIZE     | 5     | R         | [46:42]   | 0x1F      |
| Erase group size multiplier                      | ERASE_GRP_MULT     | 5     | R         | [41:37]   | 0x1F      |
| Write protect group size                         | WP_GRP_SIZE        | 5     | R         | [36:32]   | 0xF       |
| Write protect group enable                       | WP_GRP_ENABLE      | 1     | R         | [31:31]   | 0x01      |
| Manufacturer default ECC                         | DEFAULT_ECC        | 2     | R         | [30:29]   | 0x00      |
| Write speed factor                               | R2W_FACTOR         | 3     | R         | [28:26]   | 0x04      |
| Max. write data block length                     | WRITE_BL_LEN       | 4     | R         | [25:22]   | 0x09      |
| Partial blocks for write allowed                 | WRITE_BL_PARTIAL   | 1     | R         | [21:21]   | 0x00      |
| Reserved   | -                  | 4     | R         | [20:17]   | -         |
| Content protection application                   | CONTENT_PROT_APP   | 1     | R         | [16:16]   | 0x00      |
| File format group                                | FILE_FORMAT_GRP    | 1     | R/W       | [15:15]   | 0x00      |
| Copy flag (OTP)                                  | COPY               | 1     | R/W       | [14:14]   | 0x00      |
| Permanent write protection                       | PERM_WRITE_PROTECT | 1     | R/W       | [13:13]   | 0x00      |
| Temporary write protection                       | TMP_WRITE_PROTECT  | 1     | R/W/E     | [12:12]   | 0x00      |
| File format                                      | FILE_FORMAT        | 2     | R/W       | [11:10]   | 0x00      |
| ECC code   | ECC                | 2     | R/W/E     | [9:8]     | 0x00      |
| CRC  | CRC                | 7     | R/W/E     | [7:1]     | -         |
| Not used, always'1'                              | -                  | 1     | —         | [0:0]     | -         |

## 7.4 Extended CSD Register

The Extended CSD register defines the eMMC properties and selected modes. It is 512 bytes long.

The most significant 320 bytes are the Properties segment, which defines the eMMC capabilities and cannot be modified by the host. The lower 192 bytes are the Modes segment, which defines the configuration the eMMC is working in. These modes can be changed by the host by means of the SWITCH command.

R: Read only

W: One time programmable and not readable.

R/W: One time programmable and readable.

W/E: Multiple writable with value kept after power failure, H/W reset assertion and any CMD0 reset and not readable.

R/W/E: Multiple writable with value kept after power failure, H/W reset assertion and any CMD0 reset and readable.

R/W/C\_P: Writable after value cleared by power failure and HW/ rest assertion (the value not cleared by CMD0 reset) and readable.

R/W/E\_P: Multiple writable with value reset after power failure, H/W reset assertion and any CMD0 reset and readable.

W/E/\_P: Multiple writable with value reset after power failure, H/W reset assertion and any CMD0 reset and not readable

[Table 26] Extended CSD Register

| Name                                      | Field                                     | Size    | Cell Type | CSD slice | CSD Value     |
|---|---|---------|-----------|-----------|---------------|
|   |   | (Bytes) |           |           | 8 GB          |
| Reserved <sup>1</sup>                     |   | 6       | -         | [511:506] | -             |
| Extended Security Commands Error          | EXT_SECURITY_ERR                          | 1       | R         | [505]     | 0x00          |
| Supported Command Sets                    | S_CMD_SET                                 | 1       | R         | [504]     | 0x01          |
| HPI features                              | HPI_FEATURES                              | 1       | R         | [503]     | 0x01          |
| Background operations support             | BKOPS_SUPPORT                             | 1       | R         | [502]     | 0x01          |
| Max packed read commands                  | MAX_PACKED_READS                          | 1       | R         | [501]     | 0x20          |
| Max packed write commands                 | MAX_PACKED_WRITES                         | 1       | R         | [500]     | 0x20          |
| Data Tag Support                          | DATA_TAG_SUPPORT                          | 1       | R         | [499]     | 0x01          |
| Tag Unit Size                             | TAG_UNIT_SIZE                             | 1       | R         | [498]     | 0x03          |
| Tag Resources Size                        | TAG_RES_SIZE                              | 1       | R         | [497]     | 0x00          |
| Context management capabilities           | CONTEXT_CAPABILITIES                      | 1       | R         | [496]     | 0x05          |
| Large Unit size                           | LARGE_UNIT_SIZE_M1                        | 1       | R         | [495]     | 0x07          |
| Extended partitions attribute support     | EXT_SUPPORT                               | 1       | R         | [494]     | 0x03          |
| Supported modes                           | SUPPORTED_MODES                           | 1       | R         | [493]     | 0x01          |
| FFU features                              | FFU_FEATURES                              | 1       | R         | [492]     | 0x01          |
| Operation codes timeout                   | OPERATION_CODE_TIMEOUT                    | 1       | R         | [491]     | 0x11          |
| FFU Argument                              | FFU_ARG                                   | 4       | R         | [490:487] | 0x1FCA0000h   |
| Barrier support                           | BARRIER_SUPPORT                           | 1       | R         | [486]     | 0x01          |
| Reserved <sup>1</sup>                     |   | 177     | -         | [485:309] | -             |
| CMD Queuing Support                       | CMDQ_SUPPORT                              | 1       | R         | [308]     | 0x01          |
| CMD Queuing Depth                         | CMDQ_DEPTH                                | 1       | R         | [307]     | 0x1F          |
| Reserved <sup>1</sup>                     |   | 37      | -         | [306]     | -             |
| Number of FW sectors correctly programmed | NUMBER_OF_FW_SECTORS_CORRECTLY_PROGRAMMED | 4       | R         | [305:302] | 0x00          |
| Vendor proprietary health report          | VENDOR_PROPRIETARY_HEALTH_REPORT          | 32      | R         | [301:270] | 0x00          |
| Device life time estimation type B        | DEVICE_LIFE_TIME_EST_TYP_B                | 1       | R         | [269]     | 0x01          |
| Device life time estimation type A        | DEVICE_LIFE_TIME_EST_TYP_A                | 1       | R         | [268]     | 0x01          |
| Pre EOL information                       | PRE_EOL_INFO                              | 1       | R         | [267]     | 0x01          |
| Optimal read size                         | OPTIMAL_READ_SIZE                         | 1       | R         | [266]     | 0x00          |
| Optimal write size                        | OPTIMAL_WRITE_SIZE                        | 1       | R         | [265]     | 0x08          |
| Optimal trim unit size                    | OPTIMAL_TRIM_UNIT_SIZE                    | 1       | R         | [264]     | 0x01          |
| Device version                            | DEVICE_VERSION                            | 2       | R         | [263:262] | 0x01          |
| Firmware version                          | FIRMWARE_VERSION                          | 3       | R         | [261:254] | FW Patch Ver. |
| Power class for 200MHz, DDR at VCC=3.6V   | PWR_CL_DDR_200_360                        | 1       | R         | [253]     | 0x00          |
| Cache size                                | CACHE_SIZE                                | 4       | R         | [252:249] | 0x1010        |
| Generic CMD6 timeout                      | GENERIC_CMD6_TIME                         | 1       | R         | [248]     | 0x1E          |

|  |                                    |   |   |           |          |
|--|------------------------------------|---|---|-----------|----------|
| Power off notification(long) timeout                           | POWER_OFF_LONG_TIME                | 1 | R | [247]     | 0x64     |
| Background operations status                                   | BKOPS_STATUS                       | 1 | R | [246]     | 0x00     |
| Number of correctly programmed sectors                         | CORRECTLY_PRG_SECTORS-NUM          | 4 | R | [245:242] | 0x00     |
| 1st initialization time after partitioning                     | INI_TIMEOUT_AP                     | 1 | R | [241]     | 0x1E     |
| Cache Flushing Policy  | CACHE_FLUSH_POLICY                 | 1 | R | [240]     | 0x01     |
| Power class for 52MHz, DDR at 3.6V                             | PWR_CL_DDR_52_360                  | 1 | R | [239]     | 0x00     |
| Power class for 52MHz, DDR at 1.95V                            | PWR_CL_DDR_52_195                  | 1 | R | [238]     | 0x00     |
| Power class for 200MHz at Vccq=1.95V, Vcc=3.6V                 | PWR_CL_200_360                     | 1 | R | [237]     | 0x00     |
| Power class for 200MHz, at Vccq=1.3V, Vcc=3.6V                 | PWR_CL_200_195                     | 1 | R | [236]     | 0x00     |
| Minimum Write Performance for 8bit at 52MHz in DDR mode        | MIN_PERF_DDR_W_8_52                | 1 | R | [235]     | 0x00     |
| Minimum Read Performance for 8bit at 52MHz in DDR mode         | MIN_PERF_DDR_R_8_52                | 1 | R | [234]     | 0x00     |
| Reserved <sup>1</sup>  |                                    | 1 | - | [233]     | -        |
| TRIM Multiplier  | TRIM_MULT                          | 1 | R | [232]     | 0x5      |
| Secure Feature Support   | SEC_FEATURE_SUPPORT                | 1 | R | [231]     | 0x55     |
| Secure Erase Multiplier  | SEC_ERASE_MULT                     | 1 | R | [230]     | 0xA6     |
| Secure TRIM Multiplier   | SEC_TRIM_MULT                      | 1 | R | [229]     | 0xA6     |
| Boot information   | BOOT_INFO                          | 1 | R | [228]     | 0x07     |
| Reserved <sup>1</sup>  |                                    | 1 | - | [227]     | -        |
| Boot partition size  | BOOT_SIZE_MULT                     | 1 | R | [226]     | 0x20     |
| Access size  | ACC_SIZE                           | 1 | R | [225]     | 0x08     |
| High-capacity erase unit size                                  | HC_ERASE_GRP_SIZE                  | 1 | R | [224]     | 0x01     |
| High-capacity erase timeout                                    | ERASE_TIMEOUT_MULT                 | 1 | R | [223]     | 0x07     |
| Reliable write sector count                                    | REL_WR_SEC_C                       | 1 | R | [222]     | 0x01     |
| High-capacity write protect group size                         | HC_WP_GRP_SIZE                     | 1 | R | [221]     | 0x10     |
| Sleep current (VCC)  | S_C_VCC                            | 1 | R | [220]     | 0x08     |
| Sleep current (VCCQ)   | S_C_VCCQ                           | 1 | R | [219]     | 0x08     |
| Production state awareness timeout                             | PRODUCTION_STATE_AWARENESS_TIMEOUT | 1 | R | [218]     | 0x14     |
| Sleep/awake timeout  | S_A_TIMEOUT                        | 1 | R | [217]     | 0x16     |
| Sleep Notification Timeout                                     | SLEEP_NOTIFICATION_TIME            | 1 | R | [216]     | 0x10     |
| Sector Count   | SEC_COUNT                          | 4 | R | [215:212] | 0xEA0000 |
| Secure Write Protect Information                               | SECURE_WP_INFO                     | 1 | R | [211]     | 0x00     |
| Minimum Write Performance for 8bit at 52MHz                    | MIN_PERF_W_8_52                    | 1 | R | [210]     | 0x00     |
| Minimum Read Performance for 8bit at 52MHz                     | MIN_PERF_R_8_52                    | 1 | R | [209]     | 0x00     |
| Minimum Write Performance for 8bit at 26MHz, for 4bit at 52MHz | MIN_PERF_W_8_26_4_52               | 1 | R | [208]     | 0x00     |
| Minimum Read Performance for 8bit at 26MHz, for 4bit at 52MHz  | MIN_PERF_R_8_26_4_52               | 1 | R | [207]     | 0x00     |
| Minimum Write Performance                                      | MIN_PERF_W_4_26                    | 1 | R | [206]     | 0x00     |
| Minimum Read Performance                                       | MIN_PERF_R_4_26                    | 1 | R | [205]     | 0x00     |
| for 4bit at 26MHz  |                                    |   |   |           |          |
| Reserved <sup>1</sup>  |                                    | 1 | - | [204]     | -        |
| Power class for 26MHz at 3.6V 1 R                              | PWR_CL_26_360                      | 1 | R | [203]     | 0x00     |
| Power class for 52MHz at 3.6V 1 R                              | PWR_CL_52_360                      | 1 | R | [202]     | 0x00     |
| Power class for 26MHz at 1.95V 1 R                             | PWR_CL_26_195                      | 1 | R | [201]     | 0x00     |

|  |                       |   |                           |           |       |
|--|-----------------------|---|---------------------------|-----------|-------|
| Power class for 52MHz at 1.95V<br>1 R  | PWR_CL_52_195         | 1 | R                         | [200]     | 0x00  |
| Partition switching timing             | PARTITION_SWITCH_TIME | 1 | R                         | [199]     | 0x1E  |
| Out-of-interrupt busy timing           | OUT_OF_INTERRUPT_TIME | 1 | R                         | [198]     | 0x1E  |
| I/O Driver Strength                    | DRIVER_STRENGTH       | 1 | R                         | [197]     | 0x1F  |
| Device type                            | DEVICE_TYPE           | 1 | R                         | [196]     | 0x57  |
| Reserved <sup>1</sup>                  |                       | 1 | -                         | [195]     | -     |
| CSD structure                          | CSD_STRUCTURE         | 1 | R                         | [194]     | 0x02  |
| Reserved <sup>1</sup>                  |                       | 1 | -                         | [193]     | -     |
| Extended CSD revision                  | EXT_CSD_REV           | 1 | R                         | [192]     | 0x08  |
|  | Modes Segment         |   |                           |           |       |
| Command set                            | CMD_SET               | 1 | R/W/E_P                   | [191]     | 0x00  |
| Reserved <sup>1</sup>                  |                       | 1 | -                         | [190]     | -     |
| Command set revision                   | CMD_SET_REV           | 1 | R                         | [189]     | 0x00  |
| Reserved <sup>1</sup>                  |                       | 1 | -                         | [188]     | -     |
| Power class                            | POWER_CLASS           | 1 | R/W/E_P                   | [187]     | 0x00  |
| Reserved <sup>1</sup>                  |                       | 1 | -                         | [186]     | -     |
| High-speed interface timing            | HS_TIMING             | 1 | R/W/E_P                   | [185]     | 0x00  |
| Strobe Support                         | STROBE_SUPPORT        | 1 | R                         | [184]     | 0x01  |
| Bus width mode                         | BUS_WIDTH             | 1 | W/E_P                     | [183]     | 0x00  |
| Reserved <sup>1</sup>                  |                       | 1 | -                         | [182]     | -     |
| Erased memory content                  | ERASED_MEM_CONT       | 1 | R                         | [181]     | 0x00  |
| Reserved <sup>1</sup>                  |                       | 1 | -                         | [180]     | -     |
| Partition configuration                | PARTITION_CONFIG      | 1 | R/W/E &<br>R/W/E_P        | [179]     | 0x00  |
| Boot config protection                 | BOOT_CONFIG_PROT      | 1 | R/W &<br>R/W/C_P          | [178]     | 0x00  |
| Boot bus Conditions                    | BOOT_BUS_CONDITIONS   | 1 | R/W/E                     | [177]     | 0x00  |
| Reserved <sup>1</sup>                  |                       | 1 | -                         | [176]     | -     |
| High-density erase group definition    | ERASE_GROUP_DEF       | 1 | R/W/E_P                   | [175]     | 0x00  |
| Boot write protection status registers | BOOT_WP_STATUS        | 1 | R                         | [174]     | 0x00  |
| Boot area write protection register    | BOOT_WP               | 1 | R/W &<br>R/W/C_P          | [173]     | 0x00  |
| Reserved <sup>1</sup>                  |                       | 1 | -                         | [172]     | -     |
| User area write protection register    | USER_WP               | 1 | R/W<br>R/W/C_P<br>R/W/E_P | [171]     | 0x00  |
| Reserved <sup>1</sup>                  |                       | 1 | -                         | [170]     | -     |
| FW configuration                       | FW_CONFIG             | 1 | R/W                       | [169]     | 0x00  |
| RPMB Size                              | RPMB_SIZE_MULT        | 1 | R                         | [168]     | 0x20  |
| Write reliability setting register     | WR_REL_SET            | 1 | R/W                       | [167]     | 0x00  |
| Write reliability parameter register   | WR_REL_PARAM          | 1 | R                         | [166]     | 0x15  |
| Start Sanitize operation               | SANITIZE_START        | 1 | W/E_P                     | [165]     | 0x00  |
| Manually start background operations   | BKOPS_START           | 1 | W/E_P                     | [164]     | 0x00  |
| Enable background operations           | BKOPS_EN              | 1 | R/W&R/W/<br>E             | [163]     | 0x00  |
| handshake                              |                       |   |                           |           |       |
| H/W reset function                     | RST_n_FUNCTION        | 1 | R/W                       | [162]     | 0x00  |
| HPI management                         | HPI_MGMT              | 1 | R/W/E_P                   | [161]     | 0x00  |
| Partitioning Support                   | PARTITIONING_SUPPORT  | 1 | R                         | [160]     | 0x07  |
| Max Enhanced Area Size                 | MAX_ENH_SIZE_MULT     | 3 | R                         | [159:157] | 0X1D4 |
| Partitions attribute                   | PARTITIONS_ATTRIBUTE  | 1 | R/W                       | [156]     | 0x00  |

|  |                                    |    |                   |           |          |
|--|------------------------------------|----|-------------------|-----------|----------|
| Partitioning Setting                                     | PARTITION_SETTING_COMPLETED        | 1  | R/W               | [155]     | 0x00     |
| General Purpose Partition Size                           | GP_SIZE_MULT                       | 12 | R/W               | [154:143] | 0x00     |
| Enhanced User Data Area Size                             | ENH_SIZE_MULT                      | 3  | R/W               | [142:140] | 0x00     |
| Enhanced User Data Start Address                         | ENH_START_ADDR                     | 4  | R/W               | [139:136] | 0x00     |
| Reserved <sup>1</sup>                                    |                                    | 1  | -                 | [135]     | -        |
| Bad Block Management mode                                | SEC_BAD_BLK_MGMNT                  | 1  | R/W               | [134]     | 0x00     |
| Production state awareness                               | PRODUCTION_STATE_AWARENESS         | 1  | W/E_P             | [133]     | 0x00     |
| Package Case Temperature is controlled                   | TCASE_SUPPORT                      | 1  | W/E_P             | [132]     | 0x00     |
| Periodic Wake-up   | PERIODIC_WAKEUP                    | 1  | R/W/E             | [131]     | 0x00     |
| Program CID/CSD in DDR mode support                      | PROGRAM_CID_CSD_DDR_SUPPORT        | 1  | R                 | [130]     | 0x01     |
| Reserved <sup>1</sup>                                    |                                    | 2  | -                 | [129:128] | -        |
| Vendor Specific Fields                                   | VENDOR_SPECIFIC_FIELD              | 64 | <vendor specific> | [127:64]  | -        |
| Native sector size                                       | NATIVE_SECTOR_SIZE                 | 1  | R                 | [63]      | 0x00     |
| Sector size emulation                                    | USE_NATIVE_SECTOR                  | 1  | R/W               | [62]      | 0x00     |
| Sector size  | DATA_SECTOR_SIZE                   | 1  | R                 | [61]      | 0x00     |
| 1st initialization after disabling sector size emulation | INI_TIMEOUT_EMU                    | 1  | R                 | [60]      | 0x00     |
| Class 6 commands control                                 | CLASS_6_CTRL                       | 1  | R/W/E_P           | [59]      | 0x00     |
| Number of addressed groups to be Released                | DYNCAP_NEEDED                      | 1  | R                 | [58]      | 0x00     |
| Exception events control                                 | EXCEPTION_EVENTS_CTRL              | 2  | R/W/E_P           | [57:56]   | 0x00     |
| Exception events status                                  | EXCEPTION_EVENTS_STATUS            | 2  | R                 | [55:54]   | 0x00     |
| Extended Partitions Attribute                            | EXT_PARTITIONS_ATTRIBUTE           | 2  | R/W               | [53:52]   | 0x00     |
| Context configuration                                    | CONTEXT_CONF                       | 15 | R/W/E_P           | [51:37]   | 0x00     |
| Packed command status                                    | PACKED_COMMAND_STATUS              | 1  | R                 | [36]      | 0x00     |
| Packed command failure index                             | PACKED_FAILURE_INDEX               | 1  | R                 | [35]      | 0x00     |
| Power Off Notification                                   | POWER_OFF_NOTIFICATION             | 1  | R/W/E_P           | [34]      | 0x00     |
| Control to turn the Cache ON/OFF                         | CACHE_CTRL                         | 1  | R/W/E_P           | [33]      | 0x00     |
| Flushing of the cache                                    | FLUSH_CACHE                        | 1  | W/E_P             | [32]      | 0x00     |
| Control to turn the Barrier ON/OFF                       | BARRIER_CTRL                       | 1  | R                 | [31]      | 0x00     |
| Mode config  | MODE_CONFIG                        | 1  | R/W/E_P           | [30]      | 0x00     |
| Mode operation codes                                     | MODE_OPERATION_CODES               | 1  | W/E_P             | [29]      | 0x00     |
| Reserved <sup>1</sup>                                    |                                    | 2  | -                 | [28:27]   | -        |
| FFU status   | FFU_STATUS                         | 1  | R                 | [26]      | 0x00     |
| Pre-loading data size                                    | PRE_LOADING_DATA_SIZE              | 4  | R/W/E_P           | [25:22]   | 0x00     |
| Max pre-loading data size                                | MAX_PRE_LOADING_DATA_SIZE          | 4  | R                 | [21:18]   | 0x750000 |
| Product state awareness enable                           | PRODUCT_STATE_AWARENESS_ENABLEMENT | 1  | R/W/E & R         | [17]      | 0x03     |
| Secure Removal Type                                      | SECURE_REMOVAL_TYPE                | 1  | R/W & R           | [16]      | 0x01     |
| Command Queue Mode Enable                                | CMDQ_MODE_EN                       | 1  | R/W/E_P           | [15]      | 0x00     |
| Reserved <sup>1</sup>                                    |                                    | 15 | -                 | [14:0]    | -        |

**NOTE:**

1) Reserved bits should be read as "0."

## 8. AC Parameters

### 8.1 Timing Parameter

[Table 27] Timing Parameter

| Timing Parameter                         |                                       | Max. Value | Unit |
|--|---------------------------------------|------------|------|
| Initialization Time (T <sub>int</sub> )  | Normal <sup>1)</sup>                  | 1          | S    |
|  | After partition setting <sup>2)</sup> | 3          | S    |
| Read Timeout                             |                                       | 40         | mS   |
| Write Timeout                            |                                       | 640        | mS   |
| Erase Timeout                            |                                       | 1500       | mS   |
| Force Erase Timeout                      |                                       | 3          | Min  |
| Secure Erase Timeout                     |                                       | 348.6      | S    |
| Secure Trim step1 Timeout                |                                       | 348.6      | S    |
| Trim Time out                            |                                       | 1500       | mS   |
| Partition Switching Timeout (after Init) |                                       | 300        | mS   |
| Power Off Notification (Short) Timeout   |                                       | 300        | mS   |
| Power Off Notification (Long) Timeout    |                                       | 1000       | mS   |

**NOTE:**

- 1) Normal Initialization Time without partition setting
- 2) Initialization Time after partition setting, refer to INI\_TIMEOUT\_AP in 6.4 EXT\_CSD register
- 3) Be advised Timeout Values specified in Table above are for testing purposes under KONSEMI test pattern only and actual timeout situations may vary
- 4) EXCEPTION\_EVENT may occur and the actual timeout values may vary due to user environment

### 8.2 Previous Bus Timing Parameters for DDR52 and HS200 mode are defined by JEDEC standard

## 8.3 Bus Timing Specification in HS400 mode

### 8.3.1 HS400 Device Input Timing

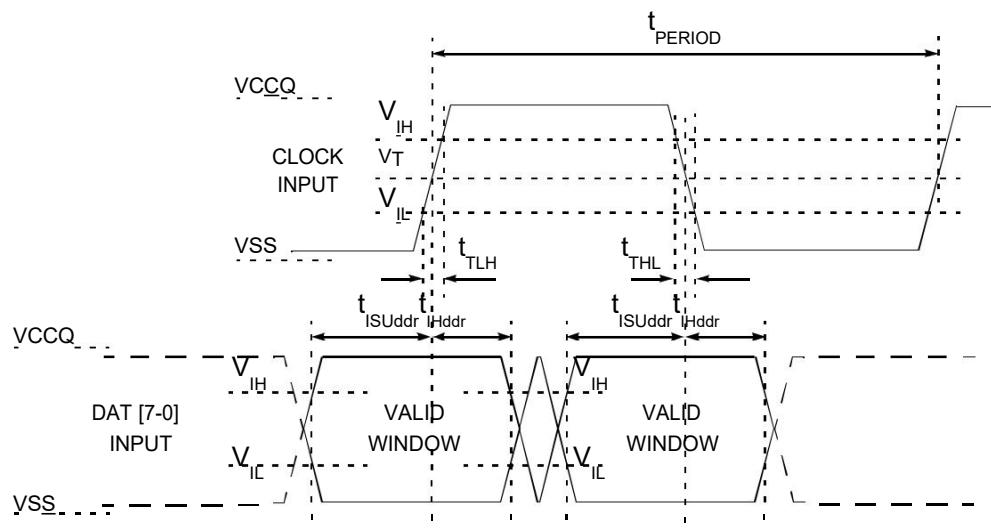


Figure 7. HS400 Device Input Timing

NOTE:

1)  $t_{\text{ISU}}$  and  $t_{\text{IH}}$  are measured at  $V_{\text{IL}}$  (max.) and  $V_{\text{IH}}$  (min.).

2)  $V_{\text{IH}}$  denotes  $V_{\text{IH}}$  (min.) and  $V_{\text{IL}}$  denotes  $V_{\text{IL}}$  (max.).

[Table 28] HS400 Device input timing

| Parameter                     | Symbol              | Min   | Max | Unit |
|-------------------------------|---------------------|-------|-----|------|
| Input CLK                     |                     |       |     |      |
| Cycle time data transfer mode | $t_{\text{PERIOD}}$ | 5     |     | nS   |
| Slew rate                     | SR                  | 1.125 |     | V/nS |
| Duty cycle distortion         | $t_{\text{CKDCC}}$  | 0.0   | 0.3 | nS   |
| Minimum pulse width           | $t_{\text{CKMPW}}$  | 2.2   |     | nS   |
| Input DAT (referenced to CLK) |                     |       |     |      |
| Input set-up time             | $t_{\text{ISUddr}}$ | 0.4   |     | nS   |
| Input hold time               | $t_{\text{IHddr}}$  | 0.4   |     | nS   |
| Slew rate                     | SR                  | 1.125 |     | V/nS |

### 8.3.2 HS400 Device Output Timing

Data Strobe is used to read data (data read and CRC status response read) in HS400 mode.

The device output value of Data Strobe is "High-Z" when the device is not in outputting data (data read, CRC status response).

Data Strobe is toggled only during data read period.

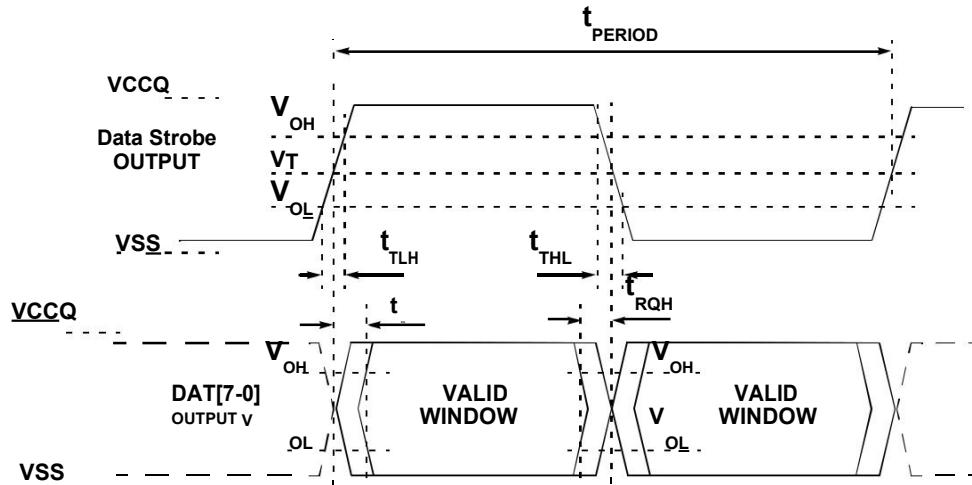


Figure . HS400 Device Output Timing

**NOTE:**

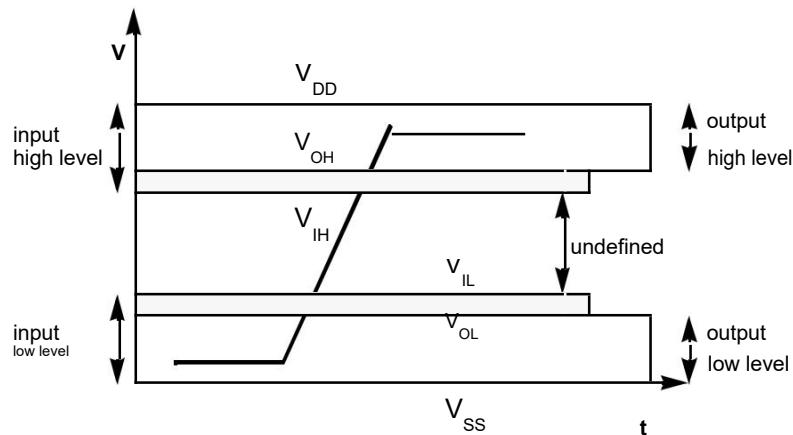
$V_{OH}$  denotes  $V_{OH}$  (min.) and  $V_{OL}$  denotes  $V_{OL}$  (max.).

[Table 29] HS400 Device Output timing

| Parameter                              | Symbol       | Min   | Max | Unit         |
|--|--------------|-------|-----|--------------|
| Data Strobe                            |              |       |     |              |
| Cycle time data transfer mode          | $t_{PERIOD}$ | 5     |     | nS           |
| Slew rate                              | SR           | 1.125 |     | V/nS         |
| Duty cycle distortion                  | $t_{DSDCD}$  | 0.0   | 0.2 | nS           |
| Minimum pulse width                    | $t_{DSMPW}$  | 2.0   |     | nS           |
| Read preamble                          | $t_{RPRE}$   | 0.4   | -   | $t_{PERIOD}$ |
| Read post-amble                        | $t_{RPST}$   | 0.4   | -   | $t_{PERIOD}$ |
| Output DAT (referenced to Data Strobe) |              |       |     |              |
| Output skew                            | $t_{RQ}$     |       | 0.4 | nS           |
| Output hold skew                       | $t_{RQH}$    |       | 0.4 | nS           |
| Slew rate                              | SR           | 1.125 |     | V/nS         |

## 8.4 Bus signal levels

As the bus can be supplied with a variable supply voltage, all signal levels are related to the supply voltage.



### 8.4.1 Open-drain mode bus signal level

[Table 30] Open-drain bus signal level

| Parameter           | Symbol   | Min            | Max. | Unit | Conditions              |
|---------------------|----------|----------------|------|------|-------------------------|
| Output High Voltage | $V_{OH}$ | $V_{DD} - 0.2$ | -    | V    | 1)                      |
| Output Low Voltage  | $V_{OL}$ | -              | 0.3  | V    | $I_{OL} = 2 \text{ mA}$ |

**NOTE:**

- 1) Because  $V_{OH}$  depends on external resistance value (including outside the package), this value does not apply as device specification.  
Host is responsible to choose the external pull-up and open drain resistance value to meet  $V_{OH}$  Min value.

### 8.4.2 Push-pull mode bus signal level eMMC

The device input and output voltages shall be within the following specified ranges for any  $V_{DD}$  of the allowed voltage range [Table 31.1] Push-pull signal level—high-voltage Range

| Parameter           | Symbol   | Min            | Max.           | Unit | Conditions                                     |
|---------------------|----------|----------------|----------------|------|--|
| Output High Voltage | $V_{OH}$ | $0.75*V_{DD}$  | -              | V    | $I_{OH} = -100\mu\text{A}@V_{CCQ} \text{ min}$ |
| Output Low Voltage  | $V_{OL}$ | -              | $0.125*V_{DD}$ | V    | $I_{OH} = 100\mu\text{A}@V_{CCQ} \text{ min}$  |
| Output High Voltage | $V_{IH}$ | $0.625*V_{DD}$ | $V_{DD} + 0.3$ | V    | -  |
| Output Low Voltage  | $V_{IL}$ | $V_{SS} - 0.3$ | $0.25*V_{DD}$  | V    | -  |

[Table 31.2] Push-pull signal level—1.70 - 1.95 V<sub>CCQ</sub> voltage Range

| Parameter           | Symbol   | Min                          | Max.                         | Unit | Conditions             |
|---------------------|----------|------------------------------|------------------------------|------|------------------------|
| Output High Voltage | $V_{OH}$ | $V_{CCQ} - 0.45\text{V}$     | -                            | V    | $I_{OH} = -2\text{mA}$ |
| Output Low Voltage  | $V_{OL}$ | -                            | $0.45\text{V}$               | V    | $I_{OL} = 2\text{mA}$  |
| Output High Voltage | $V_{IH}$ | $0.65*V_{CCQ}$ <sup>1)</sup> | $V_{CCQ} + 0.3$              | V    | -                      |
| Output Low Voltage  | $V_{IL}$ | $V_{SS} - 0.3$               | $0.35*V_{CCQ}$ <sup>2)</sup> | V    | -                      |

**NOTE:**

- 1)  $0.7*V_{CCQ}$  for MMC4.3 and older revisions.  
2)  $0.3*V_{CCQ}$  for MMC4.3 and older revisions.

## 9. DC Parameters

### 9.1 Active Power Consumption during operation

[Table 32] Active Power Consumption during operation

| Density | NAND Type | I <sub>CCQ</sub> | I <sub>CC</sub> | Unit |
|---------|-----------|------------------|-----------------|------|
| 8 GB    | 128 Gb    | 80               | 40              | mA   |

**NOTE:**

\* Power Measurement conditions: Bus configuration =x8 @HS400

\* The measurement for max RMS current is the average RMS current consumption over a period of 100ms.

### 9.2 Standby Power Consumption in auto power saving mode and standby state.

[Table 33] Standby Power Consumption in auto power saving mode and standby state

| Density | NAND Type | I <sub>CCQ</sub> |      | I <sub>CC</sub> |      | Unit |
|---------|-----------|------------------|------|-----------------|------|------|
|         |           | 25°C (Typ)       | 85°C | 25°C (Typ)      | 85°C |      |
| 8 GB    | 128 Gb    | 150              | 500  | 40              | 40   | uA   |

**NOTE:**

\*Power Measurement conditions: Bus configuration =x8, No CLK

\*Typical value is measured at Vcc=3.3V, TA=25°C. Not 100% tested.

### 9.3 Sleep Power Consumption in Sleep State

[Table 34] Sleep Power Consumption in Sleep State

| Density | NAND Type | I <sub>CCQ</sub> |      | I <sub>CC</sub> | Unit |
|---------|-----------|------------------|------|-----------------|------|
|         |           | 25°C (Typ)       | 85°C |                 |      |
| 8 GB    | 128 Gb    | 150              | 500  | 1)              | uA   |

**NOTE:**

Power Measurement conditions: Bus configuration =x8, No CLK

1) In auto power saving mode, NAND power cannot be turned off. However, in sleep mode NAND power can be turned off. If NAND power is alive, NAND power is same with that of the Standby state.

### 9.4 Supply Voltage

[Table 35] Supply voltage

| Item  | Min        | Max        | Unit |
|---|------------|------------|------|
| V <sub>DD</sub> (V <sub>CCQ</sub> ) 1.8V/3.3V | 1.70(2.70) | 1.95(3.60) | V    |
| V <sub>DDF</sub> (V <sub>CC</sub> )           | 2.7        | 3.6        | V    |
| V <sub>SS</sub>                               | -0.5       | 0.5        | V    |

## 9.5 Bus Signal Line Load

The total capacitance  $C_L$  of each line of the eMMC bus is the sum of the bus master capacitance  $C_{HOST}$ , the bus capacitance  $C_{BUS}$  itself and the capacitance  $C_{DEVICE}$  of the eMMC connected to this line:

$$C_L = C_{HOST} + C_{BUS} + C_{DEVICE}$$

The sum of the host and bus capacitance should be under 20pF.

[Table 36] Bus Signal Line Load

[Table 37] Capacitance and Resistance for HS400 mode

| Parameters                            | Symbol       | Min | Typ. | Max | Unit | Remark                                |
|---------------------------------------|--------------|-----|------|-----|------|---------------------------------------|
| Pull-up resistance for CMD            | $R_{CMD}$    | 4.7 |      | 100 | KΩ   | to prevent bus floating               |
| Pull-up resistance for DAT0-DAT7      | $R_{DAT}$    | 10  |      | 100 | KΩ   | to prevent bus floating               |
| Internal pull up resistance DAT1-DAT7 | $R_{int}$    | 10  |      | 150 | KΩ   | to prevent unconnected lines floating |
| Single Device capacitance             | $C_{DEVICE}$ |     |      | 12  | pF   |                                       |
| Maximum signal line inductance        |              |     |      | 16  | nH   | $f_{PP} \leq 52 \text{ MHz}$          |

| Parameters                           | Symbol             | Min | Typ | Max | Unit | Remark        |
|--------------------------------------|--------------------|-----|-----|-----|------|---------------|
| Bus signal line capacitance          | $C_L$              |     |     | 13  | pF   | Single Device |
| Single Device capacitance            | $C_{DEVICE}$       |     |     | 6   | pF   |               |
| Pull-down resistance for Data Strobe | $R_{Data\ Strobe}$ | 10  |     | 100 | KΩ   |               |

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